MEG II実験液体キセノンガンマ線検出器内の MPPCにおけるPDE減少の放射線源を用いた調査 Research on PDE decrease of MPPC for MEG II liquid xenon photon detector by using radiation source 12pT2-9

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Introduction



## MEG II experiment at Paul Scherrer Institute(PSI) Overview and liquid xenon photon detector(LXe)

- (LXe) COBRA superconducting magn one of charged lepton flavor violation. Pixelated timing counter (pTC) Muon stopping target  $\gamma$  are measured. Cylindrical drift chamber MPPCs Radiative decay counter (CDCH) comparing to MEG.
- MEG II experiment aims to detect  $\mu \rightarrow e\gamma$ , which is • In LXe, energy, interaction position and timing of • Detect the scintillation light( $\lambda \sim 175$ nm). • Use 4092 MPPCs and 668 PMTs. • Energy and position resolution will be improved







PDE decrease of VUV-MPPC



#### PDE decrease of VUV-sensitive MPPC cf previous talk 12pT2-8

- PDE(photon detection efficiency) decrease of VUV-MPPC is quite fast(~0.06%/hour in MEG II beam intensity)
- MEG II DAQ time: 120days/year, 3 years
- => PDE decrease is crucial problem.
- Possible cause: VUV light, gamma







- we suspected VUV light as cause of PDE decrease, but the decrease was not observed (previous talk 12pT2-8).
- PDE decrease have dependence of VUV-MPPCs' position.

=>cause of PDE decrease comes from the target.

=>we started to suspect  $\gamma$  as the cause.

2019 mass test horizontal:position of MPPCs(US:upstream of beam) red:PDE of each MPPCs, black:VUV photon fluence of those blue:γ rays dose of those



# Suspecting process of PDE decrease

We suspect surface damage.

- $\gamma$  rays deposit energy in Si and produce e- and e+.
- e- and e+ damage Si-passivation layer interface and holes are made.
- The electric field near the boundary of two surfaces will be reduced and collection efficiency will be reduced.
- Annealing is effective solution of PDE decrease( may remove holes).







Experiment



### Preparation **Setup of Irradiation to VUV-MPPC**

- Used β rays source(Sr90) to reach γ dose in MEG II DAQ in laboratory.
- Irradiation was done in HV=0
- Relative position of β source and VUV-MPPC was fixed by irradiation structure to reduce uncertainty of dose.
- Irradiation structure was put in dark box at room temperature when the irradiation was done.







### Preparation Setup of PDE measurement

- PDE was measured by Ultra-Violet light(UV, $\lambda \sim 195$ nm).
- Xenon lamp(hamamatsu) and Bandpass filter was fixed to support structure for PDE measurement.
- Relative positions of lamp and VUV-MPPC were fixed.
- Temperature at PDE measurement: 15°C
- PDE was measured for irradiated and reference VUV-MPPC.









#### Preparation calculations for irradiation dose

- Passivation layer:12mm×12mm
- Distance between MPPC and radiation source: 18mm
- $dE/dx(min)=1.664MeV*cm^2/g$  (in case of Si)
- Radiation source: Sr90,1MBq
- In this experiment, I used VUV-MPPC being removed Quartz window to ignore deposit energy in window.

=>expected dose in laboratory= 0.02Gy (in 1hours)>0.009Gy(maximum dose of some MPPC in MEG II 3years DAQ)



## Results



• About 1hours is corresponds to dose in MEG II 3years data time(120days/year)

=>Irradiated  $200 \times \gamma$  dose in MEG II 3year DAQ

• Error: considered stability of Xe-lamp









# Summary and next

- MEG II experiment aims to detect  $\mu \rightarrow e\gamma$ .
- PDE decrease of VUV-MPPC in LXe is crucial problem.
- we have suspected VUV light and  $\gamma$  ray as cause of it, and I researched about  $\gamma$  ray.
- PDE decrease of VUV-MPPC was not observed in this experiment(at room temperature,293K).
- We plan to irradiate radioactive rays at 165K(temperature of liquid xenon) to inspect whether  $\gamma$  is cause of PDE decrease in our suspecting process.





Backups



## **VUV-MPPC**

#### Normal SiPM



 insensitive to VUV lights because the protection layer and thick p+ layer absorb VUV lights before they reach player

#### VUV-MPPC

#### Quartz window



- quartz window to protect its surface instead of the protection layer
- thinner p+ layer



# Xe-lamp, Bandpass filter, and *B* source

●分光放射強度(代表値)



波長 (nm)

Hamamatsu 5W Xe-lamp(L9456-01) window material: UV glass wave length:185nm~2500nm



eSource Optics VUV Bandpass filter(25172FNB)



#### $\beta$ source(1MBq)





## Rate of source

- Used trigger scintillator(5mm×5mm and MPPC), distance between this and radiation source: 13 mm = > solid angle=0.143
- measured : 12kHz

Solid angle of VUV-MPPC = rate to VUV-MPPC=12000Hz\*(0.4/0.143)=31000Hz

It seems that estimation of source rate is not different largely.





# PDE (LED)

#### • PDE decrease was not observed





## I-V curve



